

Crystalline Materials with Anisotropic Conduction Polarities

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It is conventionally thought is that a single material will exhibit a single kind of conduction polarity, either n-type or p-type, uniformly along all directions of the crystal. Then, in all modern electronic devices, functionality is achieved by integrating together these p-type or n-type materials together. Here we will describe our recent work in the synthesis, properties, and applications of metals and semiconducting materials that exhibit either n-type or p-type conduction behavior depending on the crystallographic direction, a phenomenon we refer to as “goniopolarity”. We will establish the origin of this exotic behavior and the band structure design principles for identifying new goniopolar materials.^[1] This has led to a large expansion in the number of compounds that we have experimentally demonstrated to exhibit this effect, such as NaSn₂As₂, NaSnAs, WSi₂ and PdSe₂.^[2-5] Finally, we will show that the unique charge separation in goniopolar materials can overcome limitations of energy-harvesting technologies including thermoelectrics and photocatalysis.

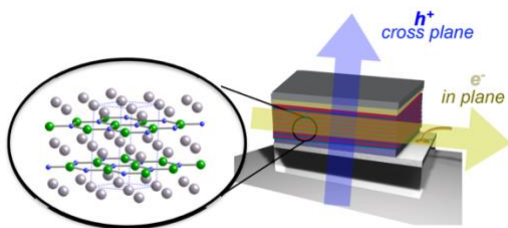


Figure 1. Schematic illustration of a layered material with axis-dependent conduction polarity.

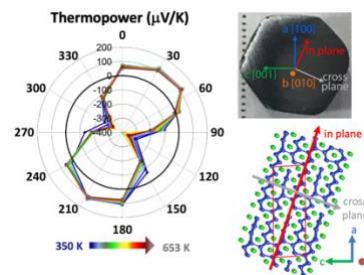


Figure 2. Thermopower polar plot of Re₄Si₇ measured from 350–650 K at different orientations along the *ac*-plane. 0° corresponds to the *a* [100] direction and the crystal is in the same orientation as the crystal cross-section and crystal structure shown on the right.

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